

Diabatic error and propagation of Majorana zero modes in interacting quantum dots systems

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Motivated by recent experimental progress in realizing Majorana zero modes (MZMs) using quantum dot systems, we investigate the diabatic errors associated with the movement of those MZMs. The movement is achieved by tuning time-dependent gate potentials applied to individual quantum dots, effectively creating a moving potential wall. To probe the optimized movement of MZMs, we calculate the experimentally accessible time-dependent fidelity and local density-of-states using many-body time-dependent numerical methods. Our analysis reveals that an optimal potential wall height is crucial to preserve the well-localized nature of the MZM during its movement. Moreover, for the first time, we analyze diabatic errors in realistic quantum-dot systems, incorporating the effects of repulsive Coulomb interactions and disorder in both hopping and pairing terms. Additionally, we provide a comparative study of diabatic errors arising from the simultaneous versus sequential tuning of multiple gates during the MZMs movement. Finally, we estimate the time scale required for MZM transfer in a six-quantum-dot system, demonstrating that MZM movement is feasible and can be completed well within the qubit's operational lifetime in practical quantum-dot setups.

I. INTRODUCTION

Majorana zero modes (MZMs) have potential applications in the development of fault-tolerant quantum computation [1–5]. The non-local encoding of information and non-Abelian exchange statistics of MZMs allow for the construction of topologically protected qubits and gates, which are immune to local perturbations and decoherence. Experimentally achieving Majorana zero modes has been studied extensively through a hybrid semiconductor nanowire or a ferro-magnetic atomic chain system with strong spin-orbit coupling placed over a superconductor [6, 7]. However, in these systems the presence of disorder and impurities continues to pose significant challenges to the formation and detection of Majorana zero modes [8–11]. Recently, a novel approach has been proposed to realize Majorana zero modes (MZMs) by utilizing a chain of quantum dots [12–14]. The experimental realization of the minimal Kitaev chain using just two quantum dots coupled with a short superconductor-semiconductor hybrid, opened a new platform to observe MZMs [15]. Remarkably, using three quantum dots, and working at the “sweet spot” $t_h = \Delta$ (where the electronic hopping t_h and superconducting coupling Δ are equal in magnitude) [16] two peaks in tunneling conductance measurements were observed interpreted as localized MZMs. Interestingly, the topological protection of MZMs increased compared to the two-site Kitaev experiments [16, 17]. Very recently, an enhancement of the excitation gap using Yu-Shiba-Rusinov states was shown experimentally in quantum-dot systems [18].

The above described quantum-dot approach provides

well-controlled setups where the effect of disorder [15–18] is significantly reduced compared to the nanowire systems. These quantum-dot systems offer a promising platform for quantum information processing with Majorana zero modes (MZMs) [19, 20], where the manipulation of MZMs can be precisely controlled using local gates. The optimal movement of Majorana zero modes (MZMs) is crucial for braiding or fusion of MZMs in the broad framework of topological quantum computation [21, 22]. However, an important issue is that the manipulation of MZMs in quantum-dot systems for such applications *must be completed within the quasiparticle “poisoning” time of the MZMs* [16]. Specifically, a rapid movement of MZMs can induce quasiparticle excitations between the ground-state manifold and the excited states, resulting in the loss of quantum information. Therefore, it is essential to manipulate MZMs within a finite window in time that (i) makes quantum computation doable, while simultaneously (ii) minimizing unwanted diabatic transitions [23–25].

For nanowire systems, the optimized transport of Majorana zero modes (MZMs) has been proposed in several studies, primarily using a single-particle formalism [26–29]. In arrays of tunable gates, the diabatic error during MZM movement has been explained using a simple Landau-Zener description [27]. For MZM transport using a single moving potential wall, it has been shown that a critical velocity, $v_{\text{crit}} = \Delta_{\text{eff}}$ (the effective gap), exists above which the moving-frame Hamiltonian becomes gapless, resulting in the loss of topological protection for MZMs [28, 30]. Recently, in non-interacting nanowire systems, it was demonstrated that an optimal number of gates is required to move MZMs effectively while minimizing diabatic error [31]. However, the diabatic error in interacting systems remains largely unexplored [32, 33], despite its significant role and impact on MZM-based quantum computing.

In this work, we analyze the diabatic errors that arise during the movement of MZMs in an interacting quantum-dot

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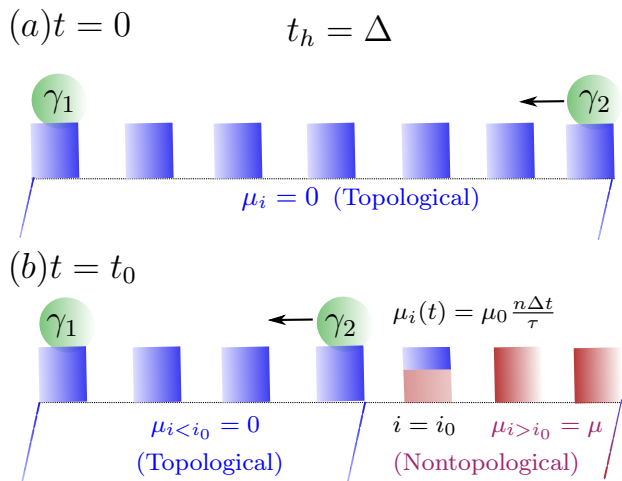


FIG. 1. Schematic representation of the movement of the right edge MZM γ_2 in a coupled quantum-dots system using individually tunable gates attached to each quantum dot. (a) At time $t = 0$, the system has two MZMs (γ_1, γ_2) located on the left and right edges of the system at the sweet-spot $t_h = \Delta$. (b) At time $t = t_0$, the right edge MZMs moved to site $i = i_0$ by using a time-dependent onsite chemical potential $\mu(t)$ (μ_0 is the height of the potential wall). The onsite chemical potential can be tuned by application of local gates attached to quantum-dots with quench rate τ . The blue color regions are topological while the red color regions are non-topological

system, employing a *many-body formalism*. Compared to nanowires, in quantum-dot systems at the sweet spot, MZMs are localized on single sites of the left and right edges of the Kitaev chain [15, 16]. To enable the movement of MZMs, we assume that each quantum dot is connected to a time-dependent gate, which modulates the local chemical potential of the individual quantum dot [21]. This modulation creates a moving potential wall (see Fig. 1) by transitioning a topological quantum dot (blue) to a non-topological quantum dot (red).

To study diabatic errors during the movement of MZMs in the quantum-dot system, we calculate the time-dependent fidelity [31] as well as the time-dependent local density-of-states (LDOS) for each quantum dot [33, 34]. First, we focus on the height of the potential wall required to move the localized MZM from one quantum dot to another. We find that optimizing the wall height is crucial to maintaining the well-localized behavior of the MZM, and measuring the local density-of-states plays a vital role in this optimization. Second, we analyze the effects of the nearest-neighbor Coulomb interaction on diabatic errors during the movement of MZMs. In realistic quantum dot systems the hopping and pairing terms may not be perfectly equal for a moderate number of quantum dots, leading to disorder in these terms [12, 16]. For this reason, we investigate the diabatic error in the presence of disorder in the hopping and pairing terms and find that the diabatic error increases very slowly for moderate disorder. However, a further increase in disorder strength leads to a jump in the diabatic error. Third, we investigate the diabatic error during

MZM movement in quantum-dot systems for the case when multiple gates are tuned simultaneously. Our results show that for slower tuning rates of the gate potentials, the diabatic error is significantly reduced in the case of multiple-gate tuning compared to single-gate tuning. Finally, using six quantum-dots, we estimate the time scale to move the MZMs in realistic quantum-dot experimental setups [16].

The organization of the manuscript is as follows. Section II introduces the interacting Kitaev model for quantum-dot systems at the sweet spot and provides details about our numerical simulations. Section III presents the results of our numerical simulations for the movement of MZMs, including the effect of the wall height (Sec. III A), nearest-neighbor Coulomb repulsion (Sec. III B), and disorder in the hopping and pairing terms (Sec. III C). Section III D compares the diabatic error during the movement of MZMs for simultaneous and sequential gate tuning. Finally, Section IV provides our conclusions and discussion. In the Appendices, we include results on the non-analytic behavior of the many-body gap (Appendix A) and the diabatic error during MZM movement in the presence of disorder in the on-site potential (Appendix B).

II. MODEL AND METHODS

We start with the one-dimensional (1D) Kitaev model for spinless fermions under open boundary condition (OBC)

$$H_0 = -t_h \sum_{i=1}^{N-1} (c_i^\dagger c_{i+1} + \text{H.c.}) + V \sum_{i=1}^{N-1} n_i n_{i+1} + \Delta \sum_{i=1}^{N-1} (c_i c_{i+1} + \text{H.c.}), \quad (1)$$

where $c_i (c_i^\dagger)$ is the fermionic annihilation (creation) operator, $n_i = c_i^\dagger c_i$ is the number operator, and t_h and Δ are the nearest-neighbour hopping and SC pairing amplitudes, respectively. Throughout the calculation, we choose $t_h = 1$ and $\Delta = t_h$ (unless stated otherwise) which is a good approximation for quantum-dot systems [15]. Using the Hamiltonian in Eq. 1, we calculate the ground state using exact diagonalization (ED) [33] and/or state-of-art density matrix renormalization group (DMRG) [35, 36]. At time $t = 0$, for the parameters $t_h = \Delta = 1$, $\mu_i = 0$, and $V = 0$, we have two onsite localized MZMs (γ_1 and γ_2) on the left and right edges of the Kitaev chain (see Fig. 1(a)). The right edge MZM (γ_2) is moved using sequential operations of the time-dependent gate potential (Fig. 1(b)). We introduce the time dependence by adding a time-dependent chemical potential in the Hamiltonian as follows [33]

III. RESULTS

$$H(t) = H_0 + \sum_i \mu_i(t) n_i \quad (2)$$

$$\mu_i(t) = \begin{cases} 0, & i < i_0 \\ \mu_0 \frac{n\Delta t}{\tau}, & \text{if } i = i_0 \\ \mu_0, & i > i_0 \end{cases} \quad (3)$$

where $\Delta t = 0.001$ is the small time step used, $1/\tau$ is the quenched rate, and n is the integer number of those steps chosen such that the chemical potential at site $i = i_0$ changes almost linearly with time from 0 to μ in a time τ , which is equivalent to the gate switching time in real experimental setups. The time-dependent onsite chemical potential can be visualized as a moving wall which grows on site $i = i_0$ in time τ and then moves to the next site and grows again, as shown in Fig. 1. This effectively results in the movement of the MZM on the right edge towards the center, while keeping the MZM at the left edge intact.

The ground state, $|\psi(0)\rangle$, of H_0 in Eq. (1) was calculated using ED/DMRG and then evolved with the time dependent Hamiltonian $H(t)$ in Eq. (3) using the time-evolution operator, $U(t) = \mathcal{T} \exp\left(-i \int_0^t H(s) ds\right)$. Numerically, the time-evolution was performed using time-dependent ED and the time-dependent variational principle (TDVP) via the ITensor Library [37]. One-dimensional chains of varying lengths up to $L = 36$ were studied and the bond dimension for DMRG calculations were kept up to $m = 120$ which ensures an accuracy involving a truncation error around 1.0×10^{-6} . The fidelity was then calculated by calculating the overlap of the ground state wave-function of the instantaneous Hamiltonian H_f with the time evolved wave-function i.e, $\mathcal{F}(t) = |\langle \psi_g(I) | \psi(t) \rangle| = |\langle \psi_g(I) | U(t) | \psi(0) \rangle|$. We then calculate the diabatic error via $f(t) = 1 - \mathcal{F}(t)$.

In addition to fidelity, we also calculate the time-dependent local density-of-states (at zero temperature). As described in Ref. [33], first we time evolve the initial state $|\psi(0)\rangle$ up to time $t = N_R \tau$, (here N_R is the number of sites where the chemical potential reaches its maximum value μ_0) using the time-dependent Hamiltonian $H(t)$ as: $|\Psi(t)\rangle = \mathcal{T} \exp\left(-i \int_0^t H(s) ds\right) |\psi(0)\rangle$, where \mathcal{T} is the time ordering operator [38]. In order to obtain the time and energy resolved local density-of-states, we calculate the double-time Green function $G(t, t')$ [39], using the instantaneous Hamiltonian $H_f = H(t = t_f)$ at time $t_f = N_R \tau$:

$$G_j^{elec}(t, t') = \langle \Psi(t) | c_j^\dagger e^{iH_f t'} c_j e^{-iH_f t} | \Psi(t) \rangle. \quad (4)$$

The time-dependent energy resolved $LDOS_{elec}(\omega, j, t)$ for electrons is given by $LDOS_{elec}(\omega, j, t) = \frac{1}{\pi} \text{Im} \int_0^T dt' e^{i(\omega + i\eta)t'} i G_j^{elec}(t, t')$. In practice, we use $T = 60$ for the integration with respect to t' , and a broadening $\eta = 0.1$. Similarly as described in Ref. [33], we also calculate the hole part of the local density-of-states $LDOS_{hole}(\omega, j, t)$. The time-dependent total local density-of-states at site j can be obtained as $LDOS(\omega, j, t) = LDOS_{hole}(\omega, j, t) + LDOS_{elec}(\omega, j, t)$.

We present the results for the movement of Majorana zero modes (MZMs) in quantum-dot systems, focusing on the effects of the wall height, the strength of the nearest-neighbor Coulomb interactions, and the effect of disorder in the hopping and pairing terms. Furthermore, we compare the diabatic error during the MZM movement when multiple gates are tuned simultaneously.

A. Effect of wall height during the movement of MZMs

In this subsection, we analyze the effect of wall height on the movement of the right edge MZM (γ_2), by varying the constant term μ_0 in Eq. 3. To move the MZM from one site to another within a finite time t , the onsite chemical potential, $\mu_i(t)$, must be larger than the critical value $\mu_c > 2t_h$ [21], in order to switch a site from a topologically nontrivial phase to a trivial phase. To track the movement of the MZM, we calculate both the time-dependent fidelity and the local density-of-states. At $t = 0$, we choose parameters $t_h = \Delta = 1$, $L = 12$, and $V = 0.05$, resulting in two localized MZMs (γ_1, γ_2) at the left and right edges of the chain, as shown in Fig. 2(a). The site-dependent local density-of-states, $LDOS(\omega, j, t)$, at $t = 0$, exhibits sharp peaks at sites $j = 1$ and 12, indicating two localized MZMs on the left and right edges of the Kitaev chain (Fig. 2(b)). The inset of Fig. 2(b) shows the electron and hole part of the local density-of-states $LDOS(\omega)$ as a function of ω for the right edge site $j = 12$ and at $t = 0$. The equal-height sharp peaks of the electron and hole components of $LDOS(\omega)$ at $\omega = 0$ confirm the presence of a localized γ_2 , on the right edge of the chain [40, 41].

As described in the previous section, the right-edge Majorana zero mode (MZM), γ_2 , can be moved via the sequential modulation of the onsite chemical potential, $\mu_i(t)$. In Fig. 2, we examine the diabatic error, $f(t)$, for three different cases where γ_2 is moved using wall heights with $\mu_0 = 3, 6$, and 12. The MZM at the right edge is transported from site $j = 12$ to $j = 6$ in the same total time T for the three cases. As shown in Fig. 2(c), the diabatic error is the smallest for $\mu_0 = 3$ and increases with higher wall heights. This behavior arises because the construction of higher walls requires a faster rate of change in $\mu_i(t)$ compared to lower walls. The sudden change in chemical potential at the start of wall formation at each site j induces oscillations in the diabatic error, $f(t)$. For faster changes in $\mu_i(t)$, these oscillations exhibit larger amplitudes due to the more pronounced nonanalytic behavior associated with a rapid modulation of the chemical potential [31, 42, 43]. Furthermore, we observe that the effective gap (defined as the energy difference between the ground state and the first excited state) shows discontinuities only at the beginning of increasing the on-site chemical potential at each site (see Fig. 6 in the Appendix A).

In Fig. 2(d), we present the real-space, time-dependent local density-of-states, $LDOS(\omega, j, t)$, for three different wall heights, $\mu_0 = 3, 6$, and 12, at time $t/\tau = 6$. Interestingly,

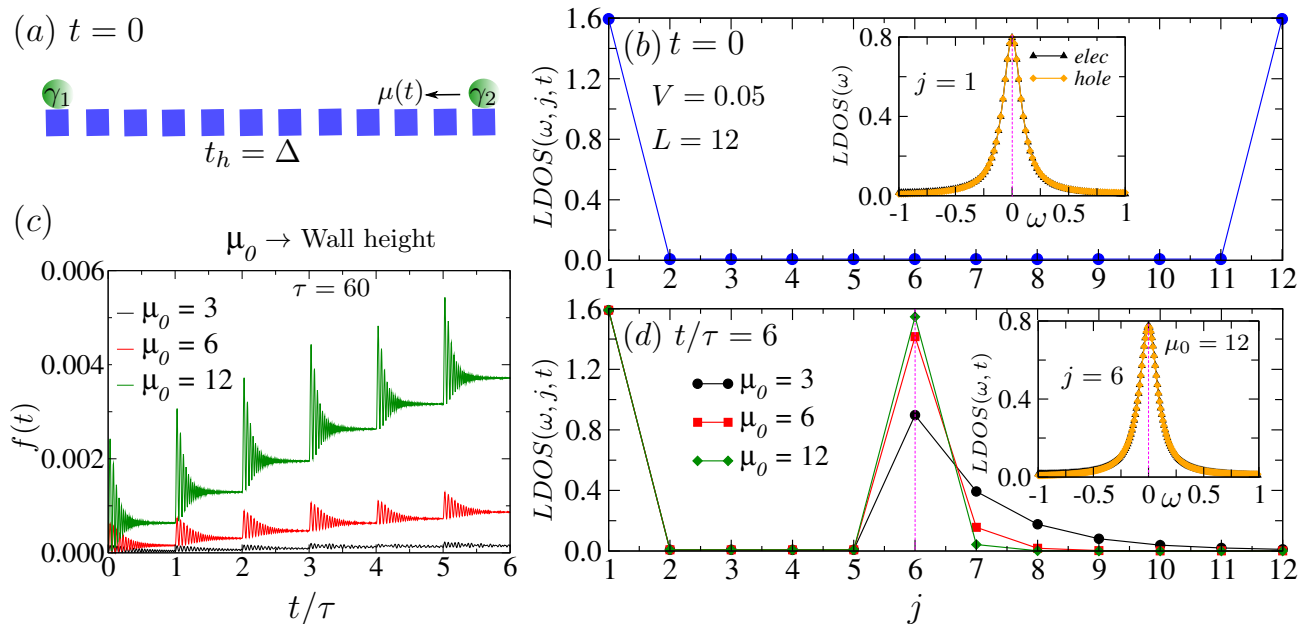


FIG. 2. (a) Schematic representation of left and right MZMs (γ_1, γ_2) at time $t = 0$ and for $L = 12$ quantum-dots at the sweet-spot $t_h = \Delta$. (b) Site-dependent local density-of-states $LDOS(\omega, j, t)$ vs site j , at $t = 0$, $\omega = 0$, and $V = 0.05$. The sharp peaks at $j = 1$ and 12 represent localized MZMs at the edge sites. The inset shows the local density-of-states $LDOS(\omega)$ vs ω at $t = 0$ for site $j = 1$. (c) The diabatic error $f(t)$ as function of t/τ for different values of μ_0 and for $\tau = 60$. (d) The site-dependent local density-of-states $LDOS(\omega, j, t)$ vs site j at time $t/\tau = 6$ for different values of μ_0 . For larger values of $\mu_0 = 12$, the MZM γ_2 is sharply localized at $j = 6$. For lower values of μ_0 , the MZM γ_2 delocalizes over a few sites, which is not a suitable case to perform real quantum computation or braiding processes. The inset shows the $LDOS(\omega, t)$ at site $j = 6$ for $\mu_0 = 12$ and $\tau = 60$ at $t/\tau = 6$.

for $\mu_0 = 3$, the right-edge MZM, γ_2 , is not well localized near the wall at site $j = 6$, even though the diabatic error is smallest in this case. As μ_0 increases from 6 to 12, the right-edge MZM, γ_2 , becomes increasingly localized at site $j = 6$ (see Fig. 2(d)). A well-localized MZM is crucial for the braiding of MZMs, as it reduces the possibility of overlap with other nearby MZMs. In the inset of Fig. 2(d), we show the time-dependent electron and hole components of the local density-of-states, $LDOS(\omega, t)$, as a function of ω at $t/\tau = 6$. The equal-height peaks of the electron and hole components of $LDOS(\omega, t)$ at $\omega = 0$ confirm the localization of γ_2 at site $j = 6$ at time $t/\tau = 6$.

The main message of this subsection is that in addition to fidelity, it is crucial to measure the local density-of-states to ensure the accurate movement of localized MZMs. Namely, fidelity alone does not provide the optimal conditions for MZM movement, as the diabatic error remains minimal for slower movement irrespective of the wall height. In contrast, the site- and time-dependent local density-of-states offers a clearer understanding of the localization or delocalization of MZMs during their transport.

B. Effect of nearest-neighbor Coulomb interactions

In this subsection, we explore the effect of repulsive nearest-neighbor Coulomb interactions, V , on the movement of the right-edge MZM, γ_2 , in a moderately sized

quantum-dot array with $L = 16$. For very small quantum dot systems, the nearest-neighbor Coulomb interactions are highly detrimental to the stability of MZMs, as the finite V leads to an overlap between the MZMs [34]. In realistic scenarios, the Coulomb interactions between neighboring quantum dots are always present. However, its influence in moderately sized quantum dot chains is not significant. This is because the nearest-neighbor Coulomb interactions, V , can be screened and minimized by the central hybrid superconducting region situated between neighboring quantum dots [44].

Figure 3(a) shows the site-dependent local density-of-states, $LDOS(\omega, j, t)$, at $t = 0$, for different values of the Coulomb interaction, V , using a system size of $L = 16$. For smaller values of V , the $LDOS(\omega = 0, j, t = 0)$ exhibits sharply localized onsite peaks at the edge sites $j = 1$ and $j = 16$. However, as V increases, the local density-of-states becomes slightly delocalized over multiple sites. In the inset of Fig. 3(a), we plot the diabatic error $f(T)$ at the final time T (when the right edge MZM γ_2 reaches site $j = 10$). In the lower panel of Fig. 3, we plot the time-dependent diabatic error, $f(t)$, for different values of V while moving the right-edge MZM, γ_2 , from site $j = 16$ to site $j = 10$. For faster movement of γ_2 (corresponding to smaller values of $\tau = 24$), the diabatic error increases more rapidly with increasing repulsive Coulomb interaction, V . This occurs because, as V increases, the effective energy gap (the difference between the ground state and the

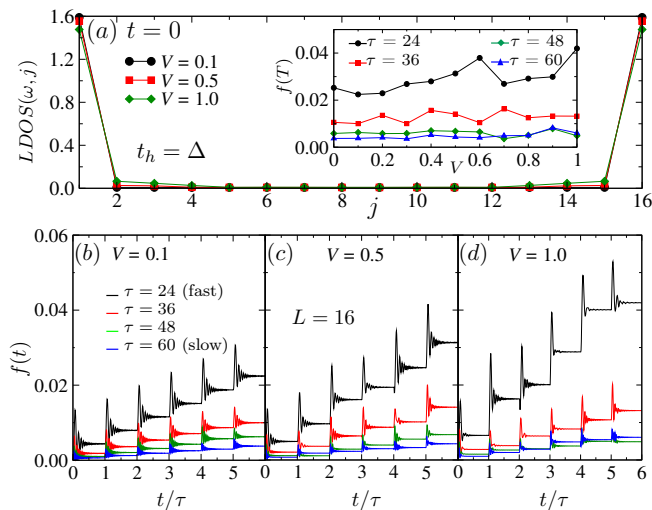


FIG. 3. (a) Site-dependent local density-of-states $LDOS(\omega, j)$ vs j at $t = 0$ and for different values of the Coulomb interaction V using a system size $L = 16$. For smaller values of $V \leq 0.1$, the MZMs are localized sharply on the edges. With an increase in V , the MZMs are localized exponentially, namely spread over a few more sites. The inset shows the $LDOS(\omega)$ vs ω for site $j = 16$ and different values of V . The diabatic error $f(t)$ vs t/τ for different values of τ and for Coulomb interactions are shown in (b) $V=0.1$, (c) $V=0.5$, and (d) $V=1.0$. The diabatic error increases with increase in V and for smaller values of τ , namely for fast movement, as intuition indicates.

first excited state) decreases [45, 46], leading to stronger interaction-induced non-adiabatic transitions. Consequently, the faster modulation of $\mu_i(t)$ causes the time-evolving state, $|\psi(t)\rangle$, to overlap with multiple higher-energy states [33]. This overlap with higher-energy states results in an increased diabatic error for smaller τ values with an increase in V [see the inset of Fig. 3(a), and Figs. 3(b,c,d)].

For $\tau > 36$, we observe that the diabatic error decreases significantly compared to the faster changes in the gate potential, $\mu_i(t)$. Interestingly, for the slow movement of the right-edge MZM, γ_2 , the diabatic error $f(T)$ does not vary significantly with increasing V up to moderate values of the Coulomb repulsion (see the inset of Fig. 3(a)). This behavior arises because the slower movement of the MZM generates fewer quasi-particle excitations above the reduced effective gap. We find that the time-evolved state, $|\psi(t)\rangle$, exhibits a very small overlap with higher-energy excited states, resulting in a very small diabatic error, $f(t)$, even as time progresses for moderate values of V (see the inset of Fig. 3(a) and the full Figs. 3(b,c,d)). These results show that in the presence of a repulsive Coulomb interaction V , we need to move the MZMs using a quite slow rate in order to minimize the diabatic error. In the presence of Coulomb repulsion, the effective gap decreases, and a faster rate of change induces more quasi-particle excitations, leading to the loss of quantum information.

C. Effect of disorder in hopping and pairing terms

Experimental systems are inevitably prone to disorder, which may add additional features to the pristine system studied in the previous sections. To understand the effect of disorder on the transport of MZMs, we here add a site-dependent disorder component in the hopping amplitude (t_h^k) as well as in the SC pairing amplitude (Δ_k) [12] drawn from a normal distribution given by

$$g(x) = \frac{1}{\sigma\sqrt{2\pi}} e^{-\frac{1}{2}\left(\frac{x-a}{\sigma}\right)^2} \quad (5)$$

where σ is the standard deviation and a is the mean of the distribution. We assume that the onsite chemical potential at time $t = 0$ is zero for each site, achievable in quantum dot experiments by tuning the gate potentials attached to individual quantum dots [16]. For the calculations, we choose the distribution to be centered around zero ($a = 0$) with different standard deviations σ up to 0.6. For the static case, the results in Ref. [12] demonstrate that even a small number of quantum dots is sufficient to support a robust pair of localized MZMs under moderate disorder, in contrast to nanowire systems. We then study the effect of disorder on the movement of the right-edge MZM, γ_2 , for a moderately sized quantum dot array with $L = 16$.

Figure 4(a) shows the site-dependent disorder averaged (using 40 realizations of disorder) $LDOS(\omega, j, t)$ at $t = 0$ for varying σ up to 0.6 and nearest-neighbour interaction $V = 0.5$. We can observe that the MZMs are still localized at the edges of the quantum-dot array but have developed a tail with finite DOS, which increases as σ increases. This is an expected behavior because MZMs are exponentially localized, with the shortest localization length for the case $t_h^k/\Delta_k = 1$. As disorder steers t_h^k/Δ_k away from unity, the localization length increases, and we start to observe the exponential tail in the $LDOS$. The inset of Fig. 4(a) shows the $LDOS$ as a function of ω for electron and hole at $j = 16$ and $\sigma = 0.6$, at $t = 0$. Again, the equal-height sharp peaks of the electron and hole portions at $\omega = 0$ confirms the presence of the localized MZM γ_2 . Additionally, we obtain a finite $LDOS$ for ω close to the SC coherence peak for the electron and hole part. This is due to the fact that the disorder introduces localized states near the SC coherence peaks, which extends into the SC gap.

Figure 4(b) shows the disorder-average diabatic error $f(t)$ acquired by the system during the movement of the MZM γ_2 from site $j = 16$ to site $j = 10$ for different values of σ up to 0.6 and a fixed $\tau = 36$. We find that the diabatic error slowly increases with time for all values of σ , but for weak disorder, such as $\sigma = 0.2$, $f(t)$ is very close to the pristine system ($\sigma = 0.0$). However, for stronger disorder, such as $\sigma = 0.6$, we found a sudden increase in the diabatic error. This is due to the fact that a strong deviation of t_h^k/Δ_k from 1 reduces the many-body gap and makes it easier to have low-energy excitations as we try to move the MZM. In Fig. 4(c) we show the $LDOS(\omega, j, t)$ for $j = 10$ at $t/\tau = 6$ and $\sigma = 0.2$ for a particular realization. We found sharp electron and hole peaks

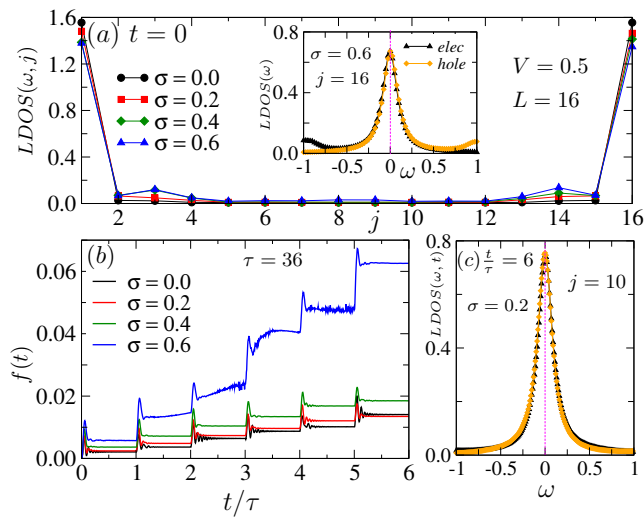


FIG. 4. (a) Site-dependent disorder averaged local density-of-states $LDOS(\omega, j)$ vs j at time $t = 0$ for different values of disorder strength σ introduced in the hoppings t_k^h and in the pairing terms Δ_k . Inset shows the $LDOS(\omega, j)$ vs ω at site $j = 16$ and for $\sigma = 0.6$. The equal-height peaks of the electron and hole parts of the $LDOS(\omega)$ illustrate the existence of MZMs in the system for $\sigma \leq 0.6$ at $t = 0$. (b) The disorder averaged diabatic error $f(t)$ in the system during movement of the right MZM γ_2 from site $j = 16 \rightarrow 10$, for different values of σ . Clearly, by increasing σ the diabatic error slowly increases with time t/τ . For $\sigma = 0.6$ the diabatic error takes a larger jump and the system displays low-quality MZMs. (c) Electron and hole parts of the time-dependent $LDOS(\omega, j, t)$ at site $j = 10$ for $\sigma = 0.2$ for a particular value of the disorder realization (taken from a Gaussian distribution).

of equal height, confirming the movement of the MZM from $j = 16$ to $j = 10$ in a time $t/\tau = 6$.

These findings highlight that quantum dot systems provide a robust platform for quantum information processing using MZMs, even in the presence of disorder, in contrast to nanowire systems [47]. For moderately sized quantum-dot systems with disorder and interactions, the diabatic error remains small during the movement of MZMs at speeds achievable in quantum-dot experiments using time-dependent gate potentials. We also calculated the diabatic error upon introducing disorder in the on-site potential and found that it remains relatively small up to moderate disorder strengths compared to semiconducting nanowire systems (details are provided in Appendix B).

D. Movement of the MZMs by Tuning Multiple Gates Simultaneously

In quantum-dot experiments, the gate attached to an individual quantum dot can be tuned either sequentially or simultaneously across multiple gates [15, 16]. In this subsection, we compare the diabatic error during the

movement of the right-edge MZM, γ_2 , for two scenarios: (i) when multiple gates are tuned simultaneously, and (ii) when the gates are tuned sequentially, one by one. To illustrate this, we consider a setup involving six quantum dots to perform the movement of the right-edge MZM, γ_2 (see Fig. 5(a)), which is experimentally feasible in current quantum-dot setups. We then tune the chemical potential, $\mu(t) = \mu_0 t/\tau$ (where $\mu_0 = 12$), of the three rightmost quantum dots simultaneously (see Fig. 5(b)) at a quench rate of $1/\tau$. We chose very small values of repulsive Coulomb interaction $V = 0.001$, to prevent the overlap of MZMs in the small system size $L = 6$ that we consider for our numerical simulation. In Fig. 5(c), we present the time-dependent, site-dependent local density-of-states, $LDOS(\omega, j, t)$, for different values of t/τ , when the three gate potentials, $\mu(t)$, are tuned simultaneously with $\tau = 36$. Interestingly, for smaller values of t/τ , the local density-of-states exhibits delocalized peaks spanning three sites, with a higher weight at site $j = 3$. At the final time, $t/\tau = 1$, the $LDOS(\omega, j, t)$ displays two localized peaks on sites $j = 1$ and $j = 3$, indicating that the right-edge MZM, γ_2 , has been successfully transferred from $j = 6$ to $j = 3$.

In Fig. 5(d), we plot the diabatic error, $f(t)$, for the movement of γ_2 under the simultaneous tuning of the chemical potential of the three quantum dots, for different values of τ . For fast movement ($\tau = 12$), the diabatic error is significantly larger and exceeds the values observed for the sequential movement of the MZM [see Fig. 5(d) and Fig. 5(e)]. This behavior is expected, as fast tuning injects a large amount of energy over a short period, leading to increased quasi-particle excitations above the gap. Consequently, the time-evolving state, $|\psi(t)\rangle$, exhibits a substantial overlap with multiple high-energy states, resulting in a larger diabatic error. For lower values of the quench rate, $1/\tau$, the diabatic error in both cases decreases to a smaller value (see Fig. 5(d)). Interestingly, the diabatic error, $f(t)$, for the simultaneous tuning of three gates is smaller (Fig. 5(d)) compared to the sequential movement of the right-edge MZM (Fig. 5(e)), even though the total time required for the sequential movement of γ_2 is three times longer than that for the simultaneous movement. This difference arises because, in the sequential movement, the energy levels undergo three distinct changes as the chemical potential, $\mu_i(t)$, is tuned one gate at a time during the movement of γ_2 . This introduces nonanalytic behavior for each gate-tuning event and leads to an accumulation of diabatic error with increase in time [31, 42, 43]. In contrast, with simultaneous multiple gate tuning (at a slower quench rate, $1/\tau$), the effective gap is modified only once, significantly reducing the occurrence of nonanalytic behavior compared to the sequential movement of γ_2 .

Next, we estimate the time scale (in SI units) required to move the right-edge MZM, γ_2 , from site $j = 6$ to $j = 3$ during the multisite tuning of gate potentials with a switching time of $\tau = 36$. Using the uncertainty relation, $\tau \hbar / \Delta_{\text{eff}}$, where the effective gap in quantum dot systems is $25 \mu\text{eV} < \Delta_{\text{eff}} < 75 \mu\text{eV}$ [15, 18], we estimate the required time to be in the range of 0.316 ns to 0.947 ns. In Ref. [16], the lifetime of the target qubit was estimated to be approximately 1 ms using a five-quantum-dot system, which is significantly larger than

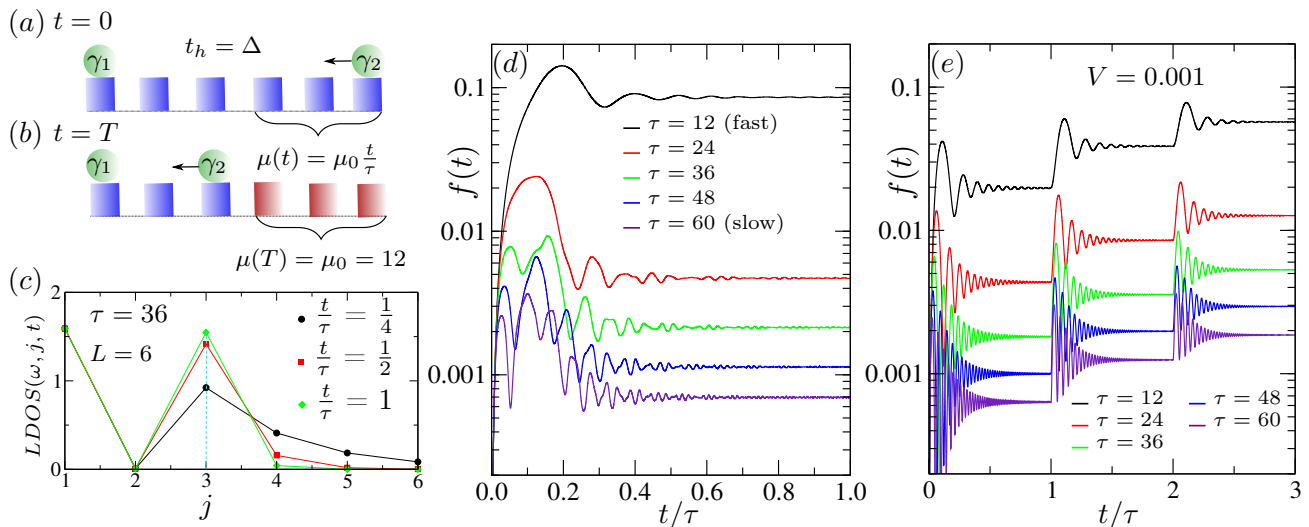


FIG. 5. Schematic of the movement of the right-edge MZM γ_2 by simultaneously tuning three gates in a six-quantum-dot system. (a) At time $t = 0$, the system contains two MZMs (γ_1, γ_2), located at the left and right edges of the system, when working at the sweet-spot $t_h = \Delta$. (b) At time $t = T$, the right-edge MZM has moved to site $j = 3$ using a simultaneous tuning of the time-dependent onsite chemical potentials, $\mu(t)$, applied to individual quantum dots. (c) Time-dependent local density-of-states, $LDOS(\omega, j, t)$, for different values of t/τ using $\tau = 36$. (d) Diabatic error, $f(t)$, for the simultaneous movement of three gate potentials as a function of t/τ and for different values of τ . (e) Diabatic error, $f(t)$, for the sequential movement of the three gate potentials as a function of t/τ and for different values of τ .

our estimated time to move the MZM, γ_2 , from site $j = 6$ to $j = 3$. For the sequential movement of the MZM, the estimated time is approximately three times longer than that for the simultaneous tuning of the three gates.

The above results demonstrate that the movement of the MZM in quantum-dot systems for quantum information processing can be completed well within the qubit lifetime [16], ensuring that it remains robust against decoherence and poisoning during the process. We also conclude that a combination of simultaneous and sequential movement of MZMs will be optimal for quantum information processing (braiding or fusion) in a network of quantum dots for topological quantum computations. The simultaneous movement of MZMs leads to delocalization over a larger number of sites, whereas the sequential movement provides better control and well-localized behavior of MZMs.

IV. CONCLUSION AND DISCUSSION

In conclusion, we investigate the diabatic errors associated with the movement of Majorana zero modes (MZMs) in quantum dot systems at the sweet spot, where the electronic hopping equals the superconducting coupling. Our findings highlight that the localized onsite nature of MZMs in quantum dots at the sweet spot, combined with the advantages of a moderately sized system, provides enhanced robustness and significantly reduces errors during MZM movement, in contrast to nanowire systems where MZMs exhibit localization but across multiple sites. Using time-dependent many-body numerical methods, we analyze the diabatic errors during MZM movement. Our results reveal that maintaining

the well-localized behavior of MZMs during movement requires an optimal potential wall height. Importantly, probing the time-dependent local density-of-states is essential for capturing the well-localized transfer of MZMs, as fidelity measurements alone are insufficient.

In the presence of nearest-neighbor repulsive Coulomb interactions, minimizing diabatic errors requires slower quench rates due to the effective gap reduction and increase in coherence length with stronger interactions. Interestingly, we find that moderate levels of disorder in hopping and pairing terms ($\sigma \leq 4$) do not significantly impact the diabatic errors. However, with further increase in disorder, we observe a sharp increase in diabatic errors, signifying MZM quality degradation caused by increased coherence length and reduced effective gap. We also observed similar trends in diabatic error for the movement of MZMs, in case of onsite quench disorder.

Our comparative study revealed that simultaneous tuning of gate potentials outperforms sequential tuning for slower quench rates, making it advantageous for efficient MZM movement. However, in quantum-dot networks designed for braiding experiments, a combination of simultaneous and sequential tuning offers greater control and better preserves the localized nature of MZMs. Such controlled movements are essential for minimizing overlaps with other MZMs, ensuring optimized quantum information processing in quantum-dot networks using MZMs.

Finally, using just six quantum-dots, we estimated the time scale to move the MZM from end sites to third sites. We show that our predicted time scale (0.3ns to 0.9ns) to move MZM in realistic setups is well within the qubit lifetime (1ms). We strongly believe that our novel theoretical results of diabatic

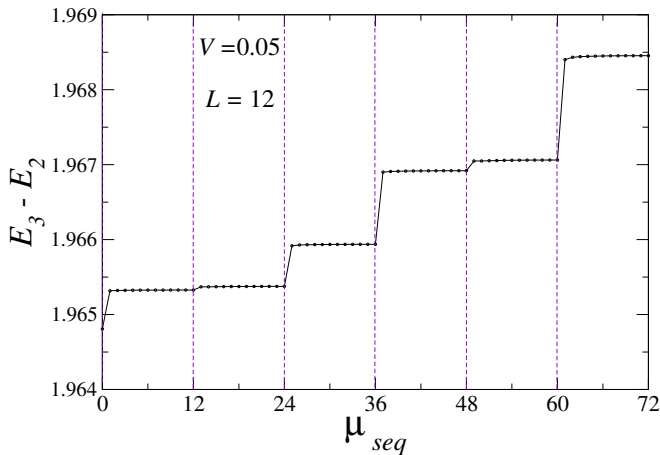


FIG. 6. Difference in many-body energy levels E_3 (first excited state above the gap) and E_2 (degenerate ground state) with change in sequential onsite chemical potential μ_i (from site $j = 12 \rightarrow 6$) as a parameter ($\mu_{seq} = \sum_i \mu_i$). For the numerical calculation, we used full diagonalization to find the many-body energy spectrum for $L = 12$ sites, working at $V = 0.05$ and $\Delta = t_h = 1$.

error for the movement of Majoranas in the one-dimensional chain will be helpful for fusion and braiding experiments in the recently developed quantum-dot setups. Our predictions, based on time-dependent LDOS and fidelity measurements, align with current experimental capabilities, paving the way for future advancements in quantum-dot-based topological quantum computation.

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Appendix A: Non-analytic behavior of many-body gap

To investigate the origin of the oscillations in the adiabatic error, we examined the variation in many-body energy levels as the static onsite chemical potential changes linearly, defined as $\mu_i = \mu_0 \cdot n/12$ (where n is an integer varying from 0 to 12). In Fig. 6, we present the energy difference between the first excited state (E_3) and the ground state (E_2), which is nearly degenerate with E_1 , as a function of the sequential total gate potential. The total gate potential is defined as $\mu_{seq} = \sum_i \mu_i$, with $\mu_0 = 12$. As illustrated in Fig. 6, the energy difference ($E_3 - E_2$) exhibits noticeable jumps or changes only at the initial stages of increasing the chemical potential (μ_i) at each site.

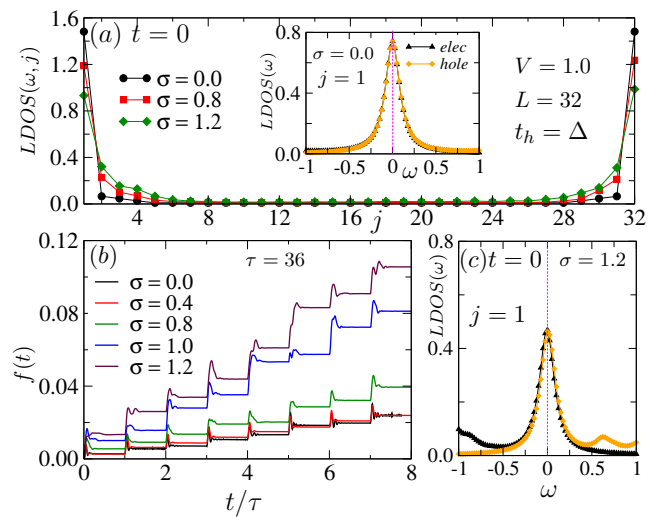


FIG. 7. Disorder averaged local density-of-states $LDOS(\omega, j)$ vs j at time $t = 0$ for different values of disorder strength σ , introduced in the onsite chemical potential μ_j , and $t_h = \Delta = 1$, $V = 1.0$, $L = 32$, $\mu_0 = 12$. Inset shows electron and hole parts of the local density-of-states $LDOS(\omega)$ vs ω at $t = 0$, $j = 1$ and for $\sigma = 0$. (c) Disordered averaged electron and hole parts of the local density-of-states $LDOS(\omega)$ vs ω at $t = 0$, $j = 1$ and for $\sigma = 1.2$. (b) The disorder averaged diabatic error $f(t)$ in the system while moving the right MZM γ_2 from site $j = 32 \rightarrow 24$, for different values of σ and with increase in time t/τ .

Appendix B: Disorder in on-site potential

Figure 7 shows the effect of disorder similar to Fig. 4 except for using *on-site disorder*. We study the movement of the right-edge MZM, γ_2 , for a moderately sized quantum dot array with $L = 32$. In Fig. 7 (a), we show the site-dependent $LDOS(\omega, j, t)$ at $t = 0$ for $t_h = \Delta = 1$ and $V = 1.0$. We found MZMs still localized at both edges but they develop a tail in the bulk, which increases with the strength of disorder. In the inset, we show the $LDOS(\omega, j, t)$ at site $j = 1$ and time $t = 0$. We found equal height electron and hole peaks, confirming the presence of MZMs. In Fig. 7(b), we show the accumulation of diabatic error with time as we move the right-edge MZM, γ_2 , from site $j = 32 \rightarrow 24$. For small and moderate values of disorder strength, namely for $\sigma = 0.4$ and 0.8 , the effect of disorder is small. For larger disorder strengths, namely for $\sigma = 1.0$ and 1.2 , the diabatic error increases fast. In Fig. 7(c) we show the $LDOS(\omega, j, t)$ for $j = 1$, $t = 0$, and $\sigma = 1.2$ for a particular realization. We still find equal height peaks for electron and hole, confirming the presence of a MZM, but the movement of these MZMs acquire large diabatic errors due to low-quality MZMs. We also see finite $LDOS$ away from $\omega = 0$ because disorder introduces localized states close to the SC coherence peaks. These results demonstrate that the diabatic error remains small up to moderate values of disorder and interactions. In contrast, for nanowire systems, the effective gap is expected to

nearly close under moderate disorder strength and for system sizes comparable to quantum-dot systems. Meanwhile, the

effective gap in quantum-dot systems remains robust under moderate disorder and interactions, resulting in lower diabatic errors compared to nanowire systems [47].

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